

Description

The DFI100FB12P3RE1 offer lower losses and higher energy for application such as motor drive, inverter and soft switching applications.



Features

- 1200V100 A, $V_{CE(sat)}(typ.) = 1.5V$
- Lower losses and higher energy
- Excellent short-circuit capability

Applications

- Motor drive
- Inverter
- Welding machines
- UPS

Circuit diagram

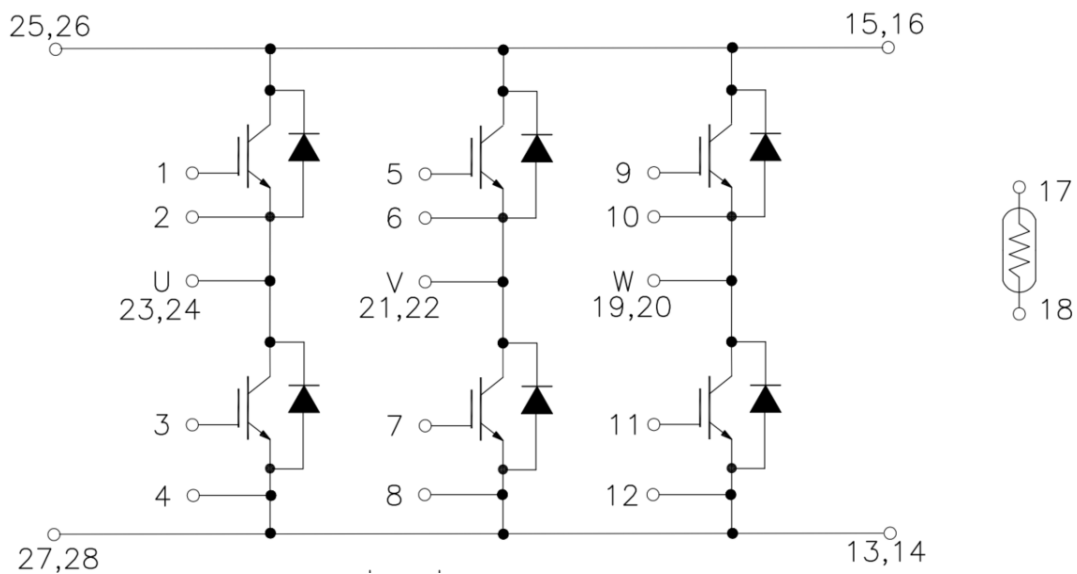


Figure 1. Out drawing & circuit diagram for DFI100FB12P3RE1

Pin Configuration and Marking Information

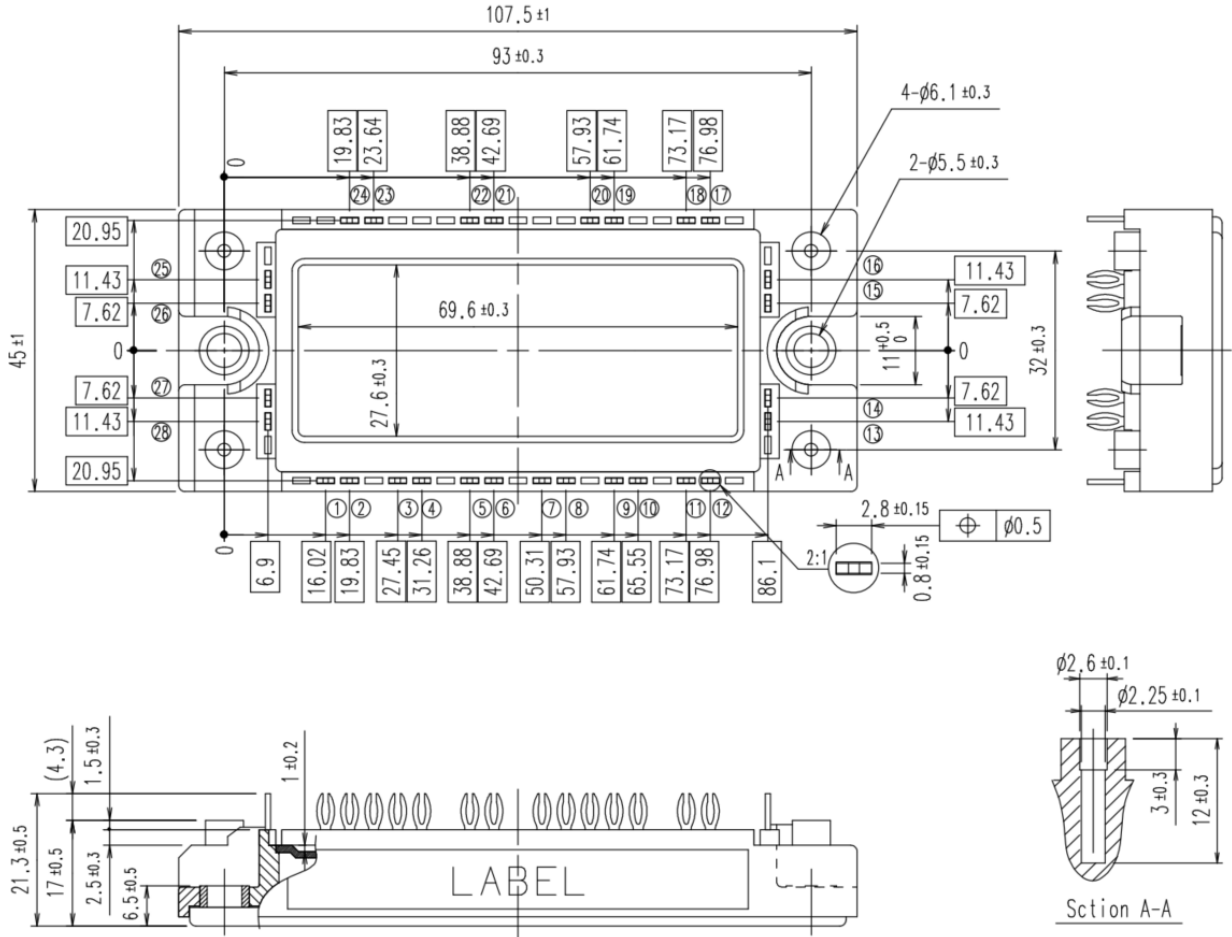


Figure 2. Pin configuration

Module

Parameter	Conditions	Value	Unit
Isolation Voltage	RMS, f = 50Hz, t = 1 min	2.5	KV
CTI	-	>200	-
Module lead resistance, terminals – chip	T _c = 25°C	0.8	mΩ
Mounting torque for module mounting	M5	3 to 6	Nm
Weight	-	175	g

Maximum Ratings (IGBT, Freewheeling Diode ,T_j=25°C unless otherwise specified)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CES}	Collector-Emitter Voltage	G-E Short	1200	V
V _{GES}	Gate-Emitter Voltage	C-E Short	±20V	V
I _C	DC Continuous Collector Current	T _C =100°C	100	A
I _{CM}	Pulse Collector Current	t _p =1ms, Note1	200	A
P _C	Maximum Power Dissipation	T _C =25°C, T _j =150°C(IGBT)	565	W
I _F	Diode forward Current	-	100	A
I _{FRM}	Repetitive peak forward Current	t _p =1ms, Note1	200	A
I ² t	I ² t-value	V _R =0V, t _p =10ms, T _j =25°C (Diode)	2000	A ² s
t _{sc}	Short Circuit Withstand Time	V _{GE} =15V, V _{CE} =600V, T _j =150°C	10	us
T _{jmax}	Max junction temperature	-	175	°C
T _{jop}	Operating junction temperature	-	-40 to 150	°C
T _{stg}	Storage temperature	-	-40 to 125	°C

Note1: Pulse width limited by maximum junction temperature

NTC characteristics

Symbol	Parameter	Condition	Value			Unit
			Min.	Typ.	Max.	
R ₂₅	Resistance	T _C =25°C	-	5	-	kΩ
ΔR/R	Deviation of R100	T _C =100°C, R ₁₀₀ =493Ω	-5	-	5	%
P ₂₅	Power dissipation	T _C =25°C	-	-	20	mW
B _{25/50}	B-value	R ₂ = R ₂₅ exp [B _{25/50} (1/T ₂ - 1/(298,15 K))]	-	3375	-	K
B _{25/80}	B-value	R ₂ = R ₂₅ exp [B _{25/80} (1/T ₂ - 1/(298,15 K))]	-	3411	-	K
B _{25/100}	B-value	R ₂ = R ₂₅ exp [B _{25/100} (1/T ₂ - 1/(298,15 K))]	-	3433	-	K

IGBT Electrical characteristics (T_j=25°C unless otherwise specified, chip)

Symbol	Item	Condition		Value			Unit
				Min.	Typ.	Max	
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C =100A V _{GE} =15V	T _j =25°C	-	1.5	-	V
			T _j =125°C	-	1.8	-	V
			T _j =150°C	-	1.9	-	V
V _{GE(th)}	Gate-Emitter threshold Voltage	I _C =5mA, V _{CE} =V _{GE}		5.0	5.8	6.8	V
Q _G	Gate charge	V _{GE} = -15V to +15V		-	895	-	nC
R _{Gint}	Internal gate resistor	f=1M, V _{pp} =1V	T _j =25°C	-	2.5	-	Ω
C _{ies}	Input Capacitance	V _{CE} =25V, V _{GE} =0V f=1MHz	T _j =25°C	-	14.4	-	nF
C _{oes}	Output Capacitance			-	0.43	-	nF
C _{res}	Reverse transfer Capacitance			-	0.35	-	nF
I _{CES}	Collector- Emitter Cut off Current	V _{CE} =1200V, V _{GE} =0V	T _j =25°C	-	-	1	mA
I _{GES}	Gate-Emitter Leakage Current	V _{GE} =20V, V _{CE} =0V	T _j =25°C	-	-	1.2	uA
t _{d(on)}	Turn-on delay time	V _{CC} =600V I _C = 100A V _{GE} =+15V/-8V R _{Gon} = R _{Goff} =5.1Ω Inductive load	T _j =25°C	-	155	-	ns
			T _j =150°C	-	191	-	
t _r	Rise time		T _j =25°C	-	75	-	ns
			T _j =150°C	-	81	-	
t _{d(off)}	Turn-off delay time		T _j =25°C	-	285	-	ns
			T _j =150°C	-	311	-	
t _f	Fall time		T _j =25°C	-	103	-	ns
			T _j =150°C	-	172	-	
E _{on}	Turn-on power dissipation		T _j =25°C	-	6.5	-	mJ
			T _j =150°C	-	11.1	-	
E _{off}	Turn-off power dissipation		T _j =25°C	-	7.1	-	mJ
			T _j =150°C	-	9.6	-	
R _{th(j-c)}	Thermal Resistance, Junction to Case (IGBT)			-	-	0.22	°C/W
R _{th(c-s)}	Thermal Resistance, Case to sink (Conductive Grease applied)			-	0.05	-	°C/W

Freewheeling Diode Electrical characteristics ($T_j=25^\circ\text{C}$ unless otherwise specified, chip)

Symbol	Item	Condition	Value			Unit	
			Min.	Typ.	Max.		
V_F	Diode Forward Voltage	$I_F=100\text{A}, V_{GE}=0\text{V}$	$T_j=25^\circ\text{C}$	-	1.5	-	V
			$T_j=150^\circ\text{C}$	-	1.3	-	
t_{rr}	Diode Reverse Recovery Time	(Switch side) $V_{CC}=600\text{V}, I_C=100\text{A}$ $V_{GE}=+15\text{V}/-8\text{V}$	$T_j=25^\circ\text{C}$		0.15		us
			$T_j=150^\circ\text{C}$		0.25		
I_{RM}	Peak reverse recovery Current	$R_{Gon} = R_{Goff} = 5.1\Omega$	$T_j=25^\circ\text{C}$	-	80	-	A
			$T_j=150^\circ\text{C}$	-	90	-	
Q_{rr}	Recovered charge	(FRD side) $V_{rr}=600\text{V}, I_F=100\text{A}$ $V_{GE}=+15\text{V}/-8\text{V}$	$T_j=25^\circ\text{C}$	-	121	-	uC
			$T_j=150^\circ\text{C}$	-	184	-	
E_{rr}	Reverse recovered energy	Inductive load switching operation	$T_j=25^\circ\text{C}$	-	3.5	-	mJ
			$T_j=150^\circ\text{C}$	-	6.1	-	
$R_{th(j-c)}$	Thermal Resistance, Junction to Case (Diode)		-	-	0.31	$^\circ\text{C}/\text{W}$	
$R_{th(c-s)}$	Thermal Resistance, Case to sink (Conductive Grease applied)		-	0.05	-	$^\circ\text{C}/\text{W}$	

Test Conditions

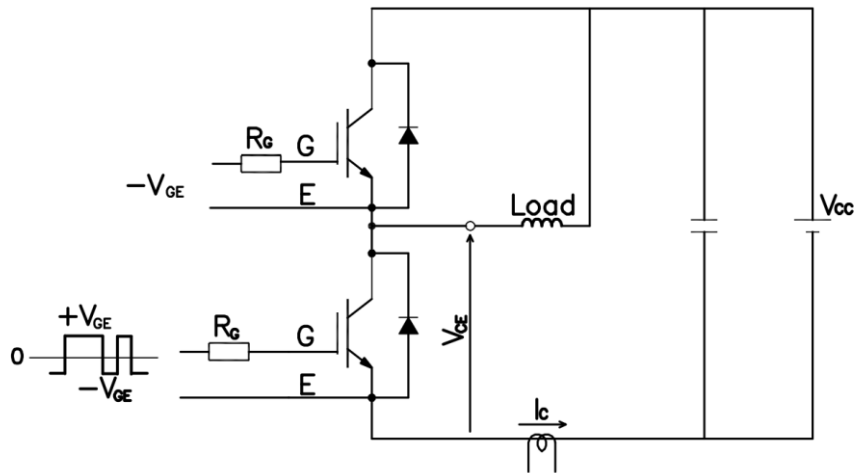


Figure 3. Switching time measure circuit

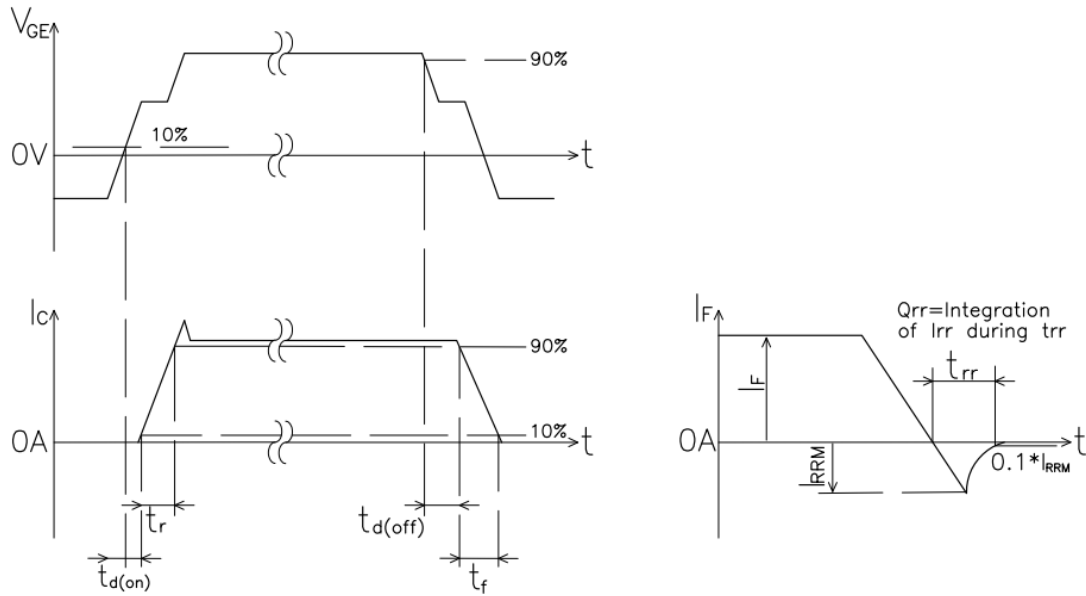
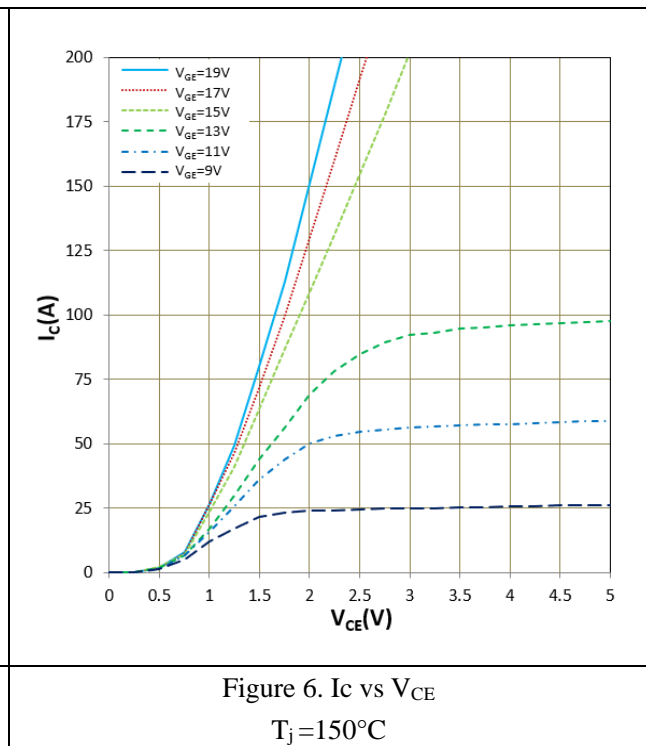
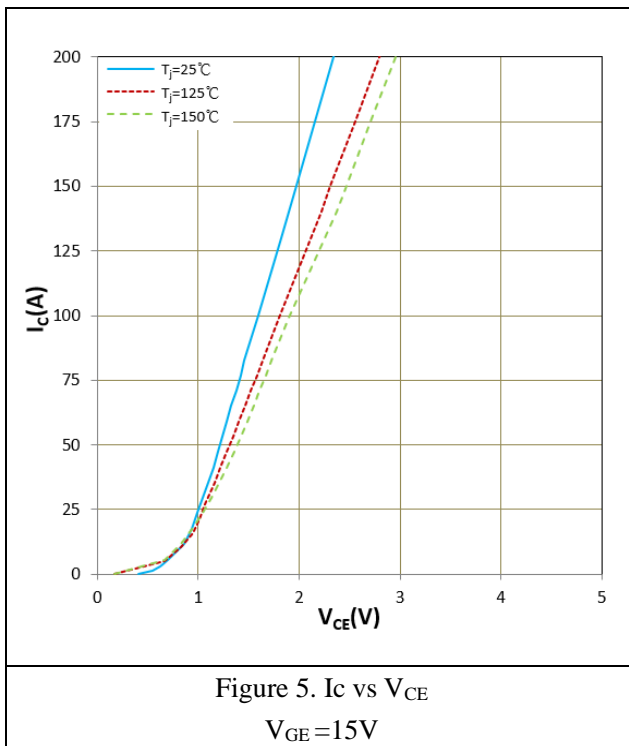


Figure 4. Switching time definition



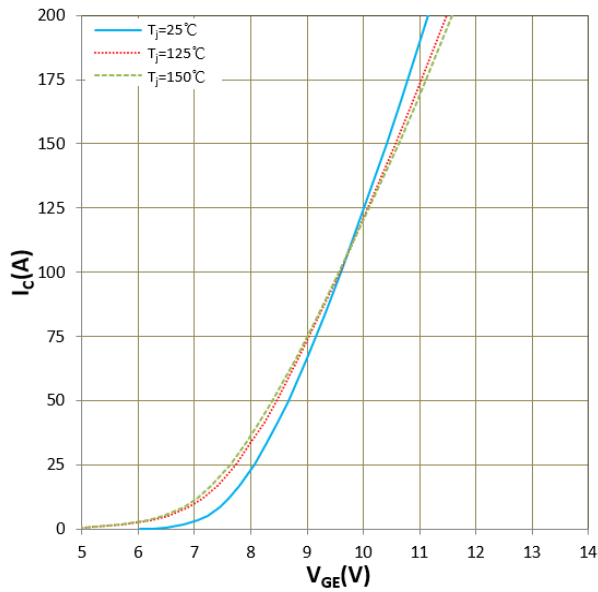


Figure 7. I_c vs V_{GE}
 $V_{CE}=15V$

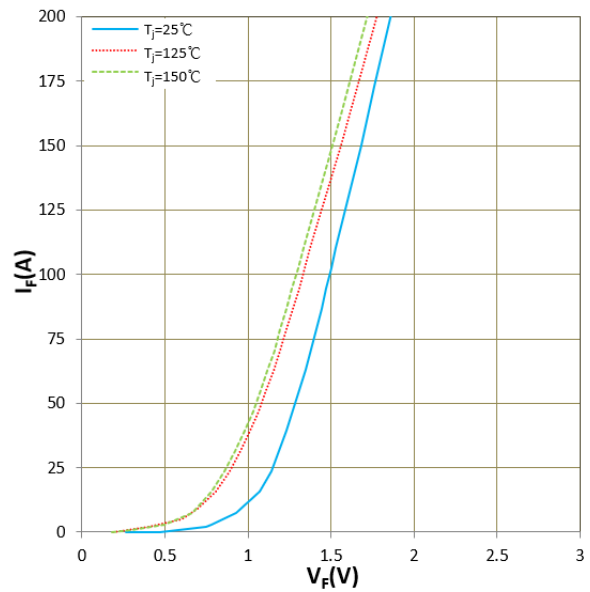


Figure 8. I_F vs V_F

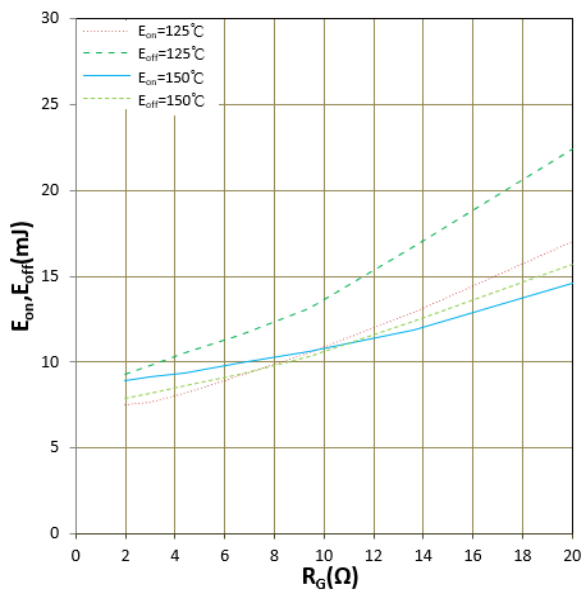


Figure 9. E_{on} , E_{off} vs R_G (Typ)
 $V_{CC}=600V$, $V_{GE}=+15V/-8V$, $I_C = 100A$
Inductive Load

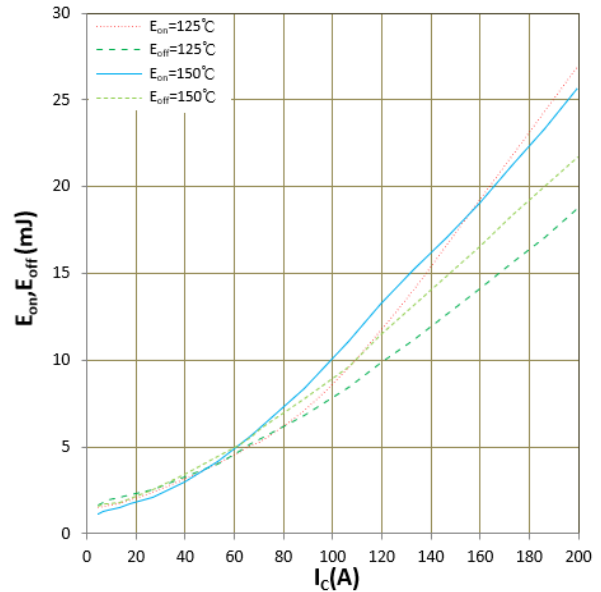


Figure 10 E_{on} , E_{off} vs I_c (Typ)
 $V_{CC}=600V$, $V_{GE}=+15V/-8V$, $R_{Gon} = R_{Goff}=5.1\Omega$
Inductive Load

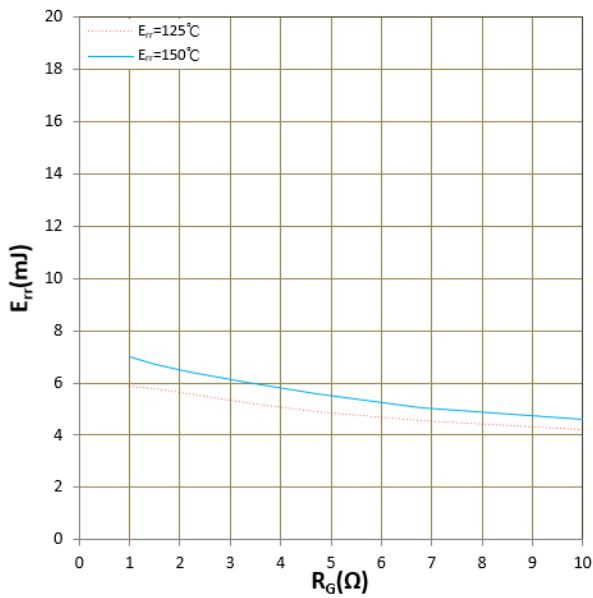


Figure 11. Err vs R_G(Typ)
V_{CC}=600V, V_{GE}=+15V/-8V, I_F =100A
Inductive Load

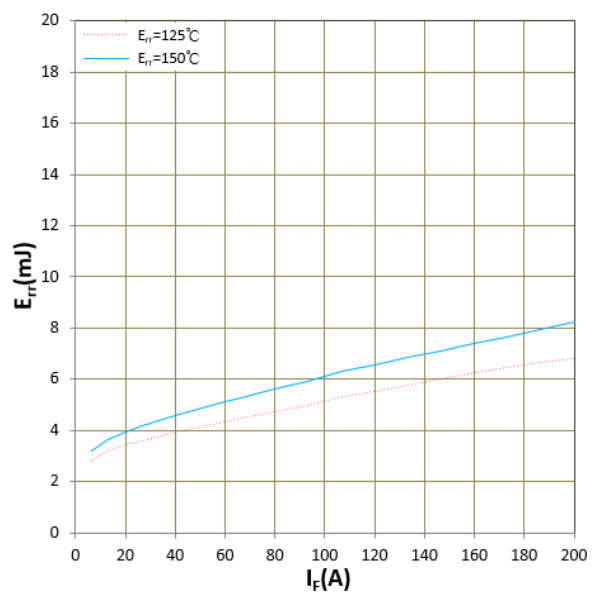


Figure 12. Err vs I_F(Typ)
V_{CC}=600V, V_{GE}=+15V/-8V, R_{Gon} = R_{Goff}=5.1Ω
Inductive Load

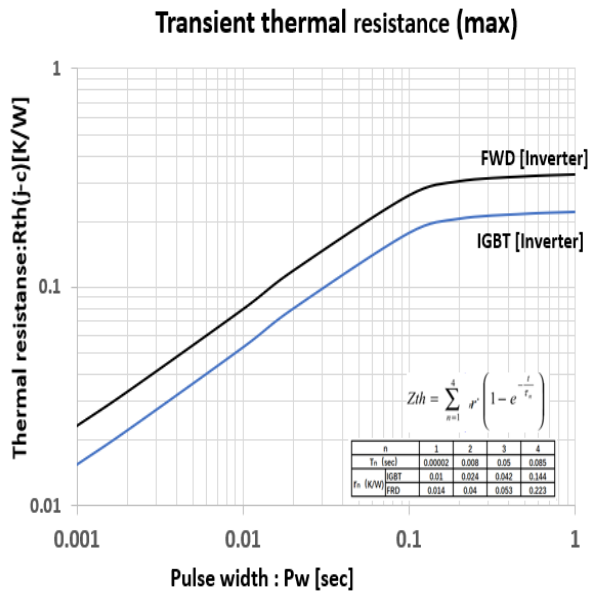


Figure 13. Transient thermal resistance

IMPORTANT NOTICE:

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The data contained in this document is exclusively intended for technically trained staff. You and your technical departments will have to evaluate the product's suitability for the intended application and the completeness of the product data concerning such application.

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